

## 650V SiC Schottky Diode

VDC	650 V
Q <sub>C</sub>	36 nC
I <sub>F</sub>	12 A
T <sub>j,max</sub>	175 °C

### Amp+™ Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- Fast, temperature-independent switching
- Avalanche tested to 80mJ\*

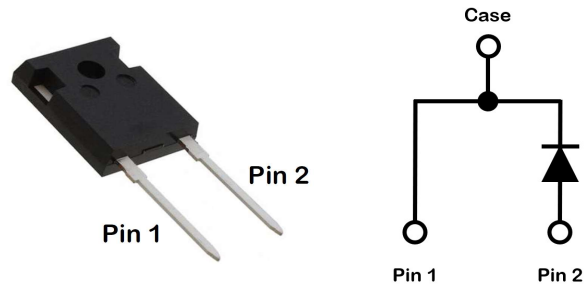
### Amp+™ Benefits

- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

### Amp+™ Applications

- Switch mode power supplies, UPS
- Power factor correction
- EV charging stations
- Output rectification

### Package



Part #	Package	Marking
GP3D012A065B	TO-247-2L	3D012A065



### Maximum Ratings, at T<sub>j</sub>=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit
Continuous forward current	I <sub>F</sub> **	T <sub>C</sub> =25 °C, T <sub>J</sub> =175 °C	37	A
		T <sub>C</sub> =125 °C, T <sub>J</sub> =175 °C	19	
		T <sub>C</sub> =150 °C, T <sub>J</sub> =175 °C	12	
Surge non-repetitive forward current sine halfwave	I <sub>FSM</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	120	A
		T <sub>C</sub> =110 °C, t <sub>p</sub> =8.3 ms	96	
Non-repetitive peak forward current	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =10 μs	720	A
i <sup>2</sup> t value	∫i <sup>2</sup> dt	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	60	A <sup>2</sup> s
		T <sub>C</sub> =110 °C, t <sub>p</sub> =8.3 ms	38	
Repetitive peak reverse voltage	V <sub>RRM</sub>	T <sub>J</sub> =25 °C	650	V
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns
Power dissipation	P <sub>tot</sub> **	T <sub>C</sub> =25 °C	124	W
Operating junction & storage temperature	T <sub>j</sub> , T <sub>storage</sub>	Continuous	-55...175	°C
Soldering temperature	T <sub>solder</sub>	Wave soldering leads	260	°C
Mounting torque		M3 Screw	1	N-m

**Notes:**

\* EAS of 80 mJ is based on starting T<sub>J</sub> = 25°C, L = 1.0 mH, IAS = 12.65 A, V = 50 V.

\*\* Typical R<sub>thJC</sub> used

Electrical Characteristics, at  $T_j=25\text{ }^\circ\text{C}$ , unless otherwise specified

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	$V_{DC}$	$T_j=25\text{ }^\circ\text{C}$	650	-	-	V
Diode forward voltage	$V_F$	$I_F=12\text{A}, T_j=25\text{ }^\circ\text{C}$	-	1.42	1.50	V
		$I_F=12\text{A}, T_j=125\text{ }^\circ\text{C}$	-	1.49	-	
		$I_F=12\text{A}, T_j=175\text{ }^\circ\text{C}$	-	1.60	1.90	
Reverse current	$I_R$	$V_R=650\text{V}, T_j=25\text{ }^\circ\text{C}$	-	2	30	$\mu\text{A}$
		$V_R=650\text{V}, T_j=125\text{ }^\circ\text{C}$	-	14	-	
		$V_R=650\text{V}, T_j=175\text{ }^\circ\text{C}$	-	47	300	
Total capacitive charge	$Q_C$	$V_R=400\text{V}, T_j=25\text{ }^\circ\text{C}$	-	36	-	nC
Total capacitance	C	$V_R=1\text{V}, f=1\text{ MHz}$	-	572	-	pF
		$V_R=200\text{V}, f=1\text{ MHz}$	-	68	-	
		$V_R=400\text{V}, f=1\text{ MHz}$	-	57	-	

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Thermal resistance, junction-case	$R_{thJC}$	-	-	1.21	1.48	$^\circ\text{C/W}$

Typical Performance

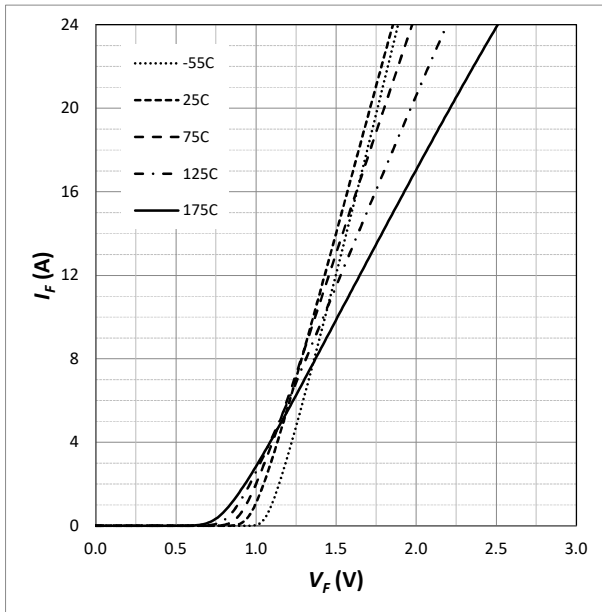


Fig. 1 Forward Characteristics (parameterized on  $T_j$ )

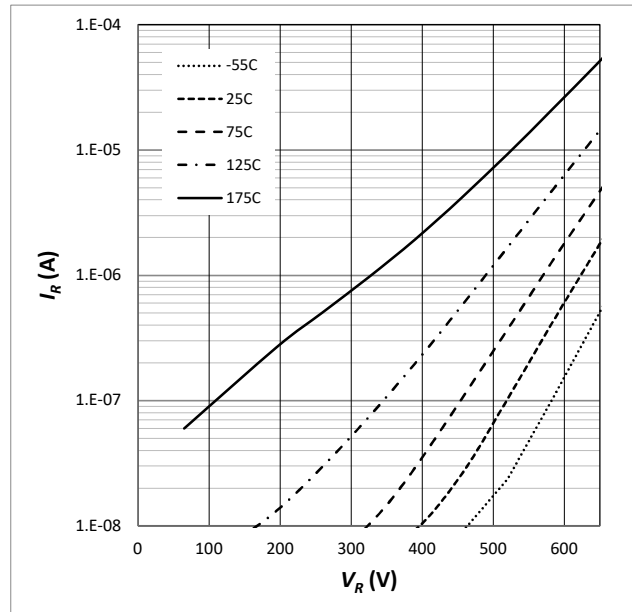


Fig. 2 Reverse Characteristics (parameterized on  $T_j$ )

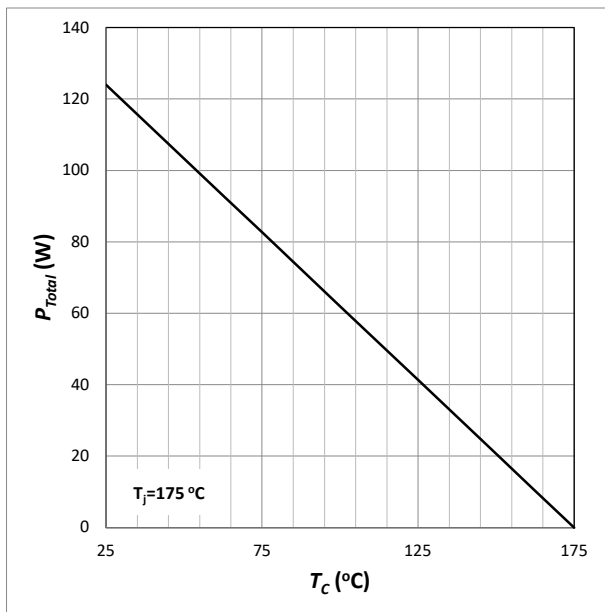


Fig. 3 Power Derating

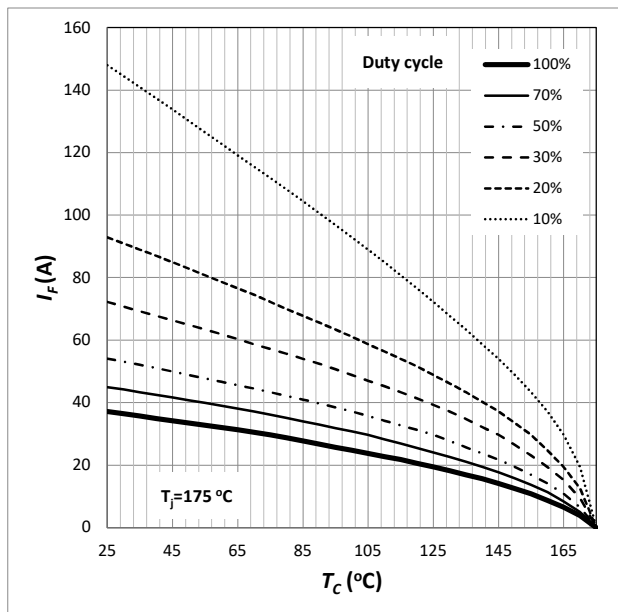


Fig. 4 Current Derating

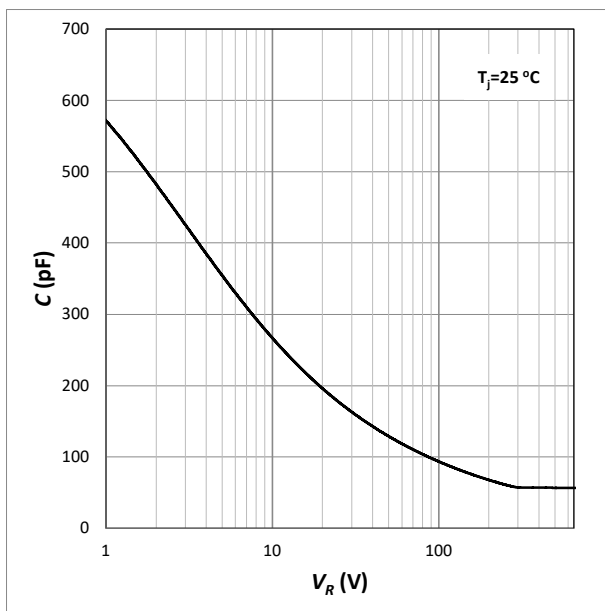


Fig. 5 Capacitance

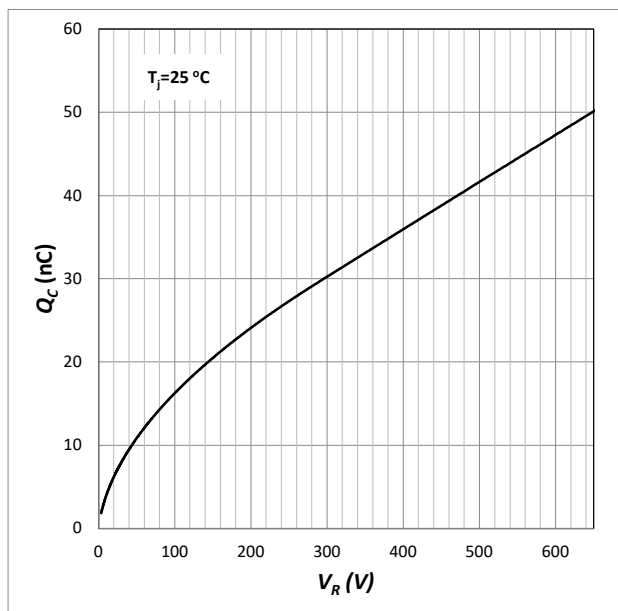


Fig. 6 Capacitive Charge

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Amp+™

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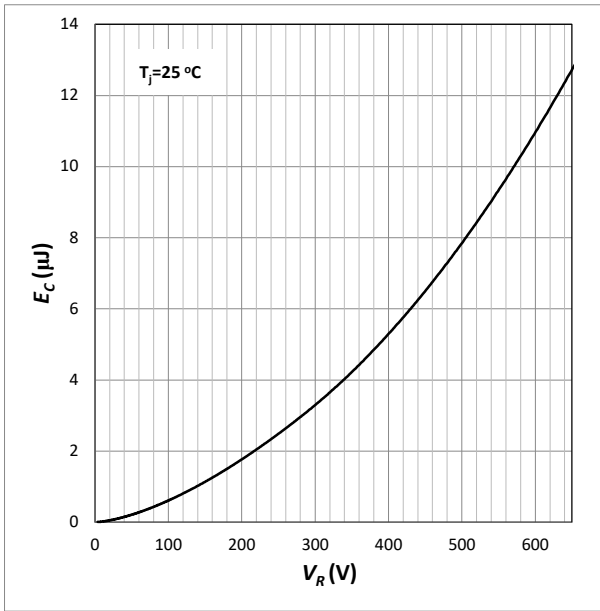


Fig. 7 Typical Capacitance Stored Energy

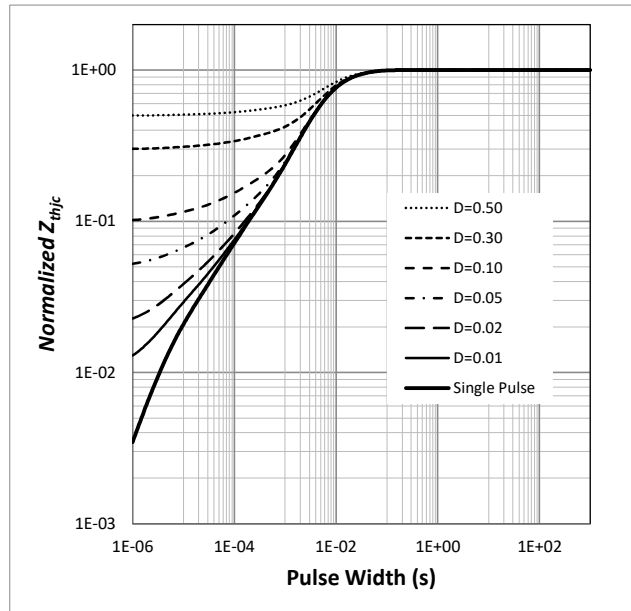
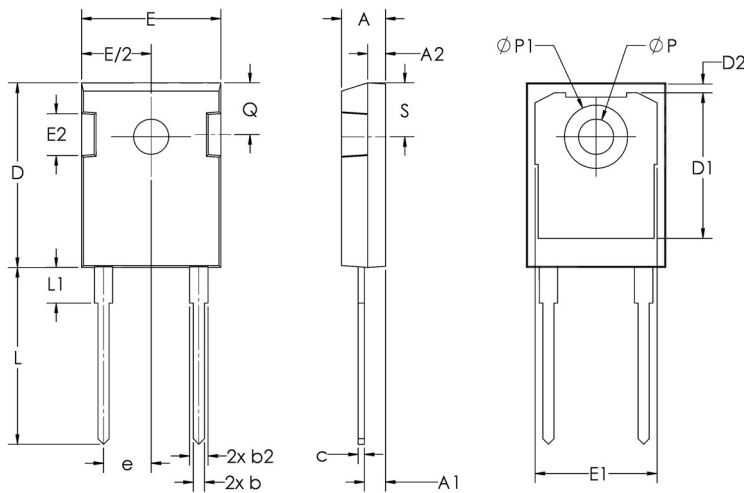


Fig. 8 Transient Thermal Impedance

## Package Dimensions TO-247-2L



Sym	Millimeters		Inches	
	Min	Max	Min	Max
A	4.70	5.31	0.185	0.209
A1	2.21	2.59	0.087	0.102
A2	1.50	2.49	0.059	0.098
b	0.99	1.40	0.039	0.055
b2	1.65	2.39	0.065	0.094
c	0.38	0.89	0.015	0.035
D	20.80	21.46	0.819	0.845
D1	13.08	17.65	0.515	0.695
D2	0.51	1.35	0.020	0.053
E	15.49	16.26	0.610	0.640
E1	13.46	14.16	0.530	0.557
E2	3.43	5.49	0.135	0.216
e	5.44 BSC		.214 BSC	
L	19.81	20.32	0.780	0.800
L1	4.10	4.50	0.161	0.177
ØP	3.56	3.66	0.140	0.144
ØP1	7.06	7.39	0.278	0.291
Q	5.38	6.20	0.212	0.244
S	6.04	6.30	0.238	0.248

## Notes

### **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of [www.SemiQ.com](http://www.SemiQ.com).

### **REACH Compliance**

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